

Description

The DCSM07L is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast re-sponse time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DCSM07L complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 25\text{kV}$ contact discharge. It is assembled into an ultra-small SOT-23 lead-free package. The small size and high ESD surge protection make DCSM07L an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- ◆ 100W peak pulse power(8/20 μs)
- ◆ Protects one two uni-directional line(s)
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 7V
- ◆ Low clamping voltage
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: $\pm 30\text{kV}$
Contact discharge: $\pm 25\text{kV}$
 - IEC61000-4-5 (Lighting) 5A (8/20 μs)
- ◆ RoHS Compliant

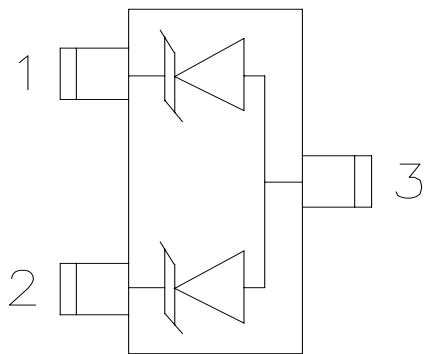
Mechanical Characteristics

- ◆ Package: SOT-23
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

Applications

- ◆ Peripherals
- ◆ Industrial Equipment
- ◆ Notebook Computers
- ◆ Portable Instrumentation
- ◆ Microprocessor Based Equipment
- ◆ Cell Phone Handsets and Accessories
- ◆ Personal Digital Assistants(PDAs) and Pagers

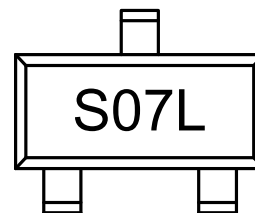
Dimensions and Pin Configuration



SOT23

Circuit and Pin Schematic

Marking Information



S07L = Device Marking Code

Ordering Information

Part Number	Marking	Packaging	Reel Size
DCSM07L	S07L	3000/Tape & Reel	7 inch

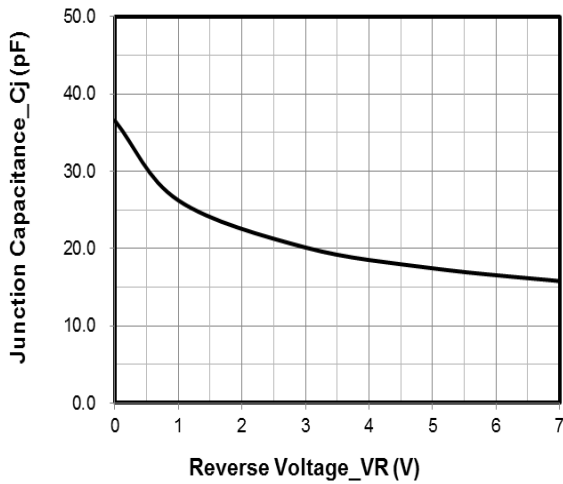
Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	100	W
Peak Pulse Current (8/20 μs)	Ipp	5	A
ESD per IEC 61000-4-2 (Air)	VESD	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 25	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

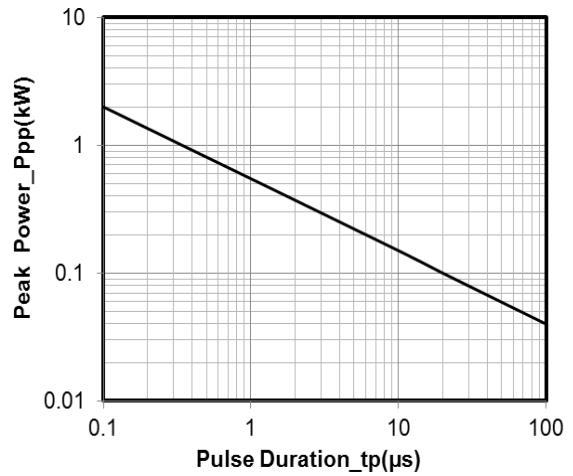
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			7	V	
Reverse Breakdown Voltage	VBR	7.5			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.5	μA	VRWM = 7V, any I/O pin to ground
Clamping Voltage	VC			15	V	I _{PP} = 1A (8 x 20 μs pulse), any I/O pin to ground
Clamping Voltage	VC			20	V	I _{PP} = 5A (8 x 20 μs pulse), any I/O pin to ground
Junction Capacitance	CJ		35		pF	VR = 0V, f = 1MHz, any I/O pin to ground

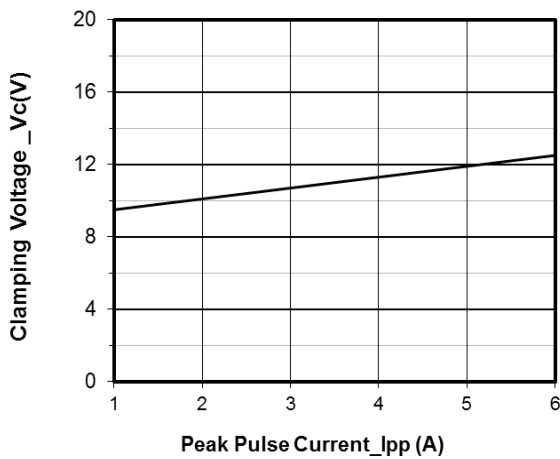
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



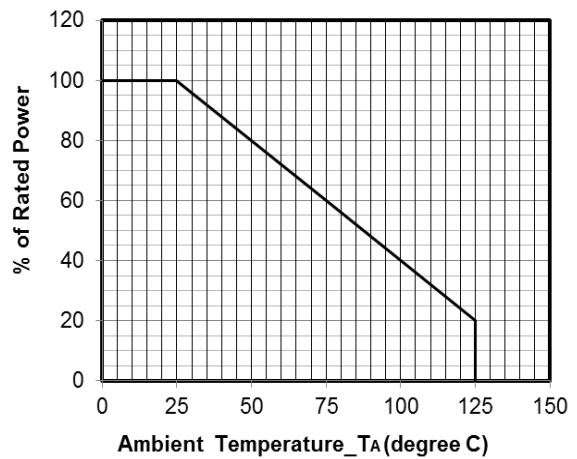
Junction Capacitance vs. Reverse Voltage



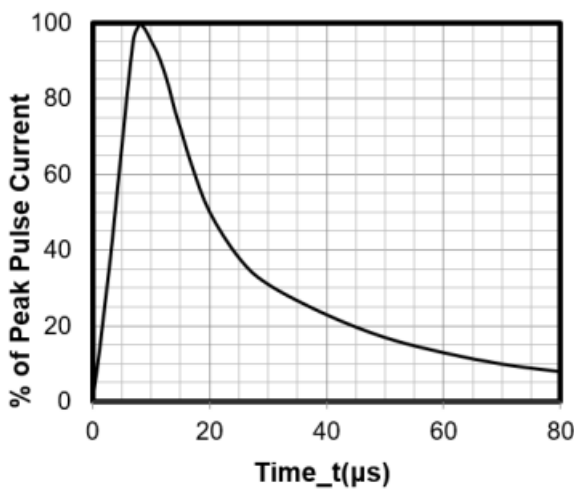
Peak Pulse Power vs. Pulse Time



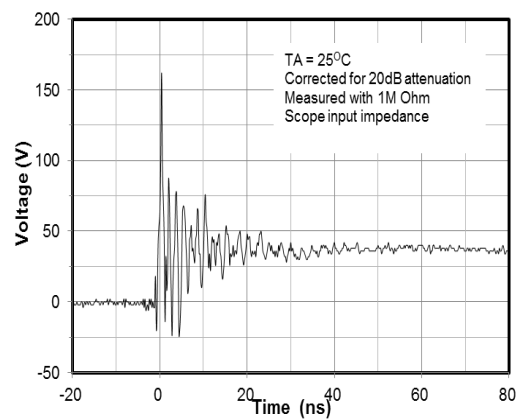
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



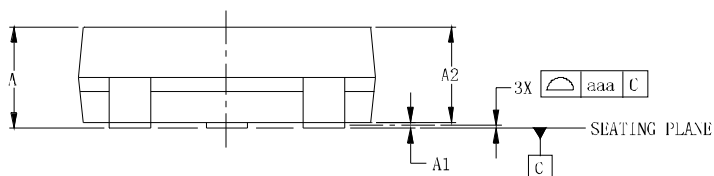
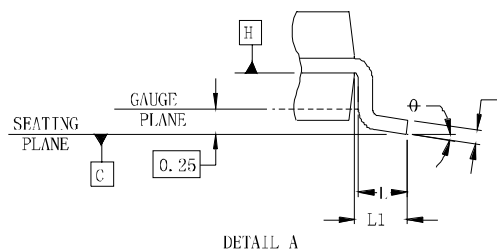
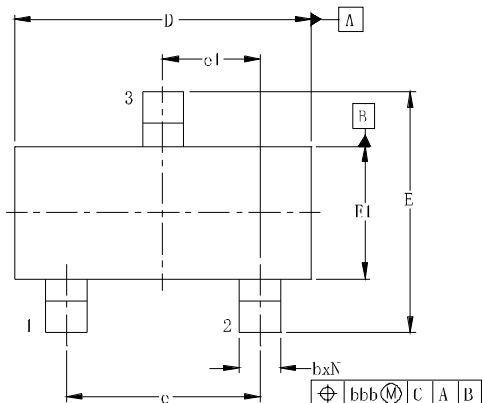
8 X 20μs Pulse Waveform



ESD Clamping Voltage

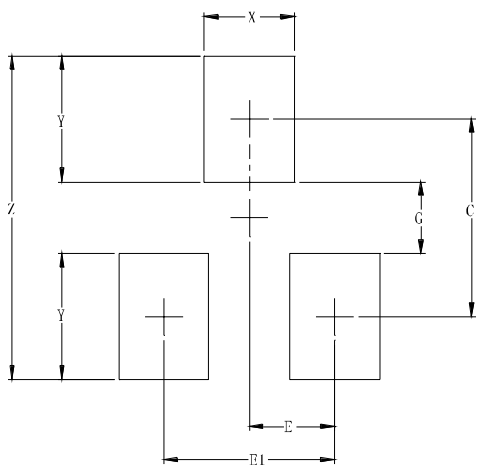
8 kV Contact per IEC61000-4-2

SOT-23 Package Outline Drawing



DIMENSIONS						
SYM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.035	-	0.044	0.89	-	1.12
A1	0.000	-	0.004	0.01	-	0.10
A2	0.035	0.037	0.040	0.88	0.95	1.02
b	0.012	-	0.020	0.30	-	0.51
c	0.003	-	0.007	0.08	-	0.18
D	0.110	0.114	0.120	2.80	2.90	3.04
E	0.082	0.093	0.104	2.10	2.37	2.64
E1	0.047	0.051	0.055	1.20	1.30	1.40
e	0.075			1.90BSC		
e1	0.037			0.95BSC		
L	0.015	0.020	0.024	0.40	0.50	0.60
L1	0.022			0.55		
N	3			3		
ϕ	0°	-	8°	0°	-	8°
aaa	0.004			0.10		
bbb	0.008			0.20		

Suggested Land Pattern



DIMENSIONS		
SYM	INCHES	MILLIMETERS
C	0.087	2.20
E	0.037	0.95
E1	0.075	1.90
G	0.031	0.80
X	0.039	1.00
Y	0.055	1.40
Z	0.141	3.60

Contact Information

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